



HIGH-PERFORMANCE SCHOTTKY



Offering low forward voltage drop and excellent high temperature stability, these devices are ideal for space constrained applications where small footprint and low profile is desired.

VRRM	lo	VF Max.	IR Max	U-DFN3030-4	
V	Α	V	μΑ		
60	0.5	0.49	100	SBR05M60BLP	
100	0.5	0.73	25	SBR05M100BLP	
	1	0.82	25	SBR1M100BLP	

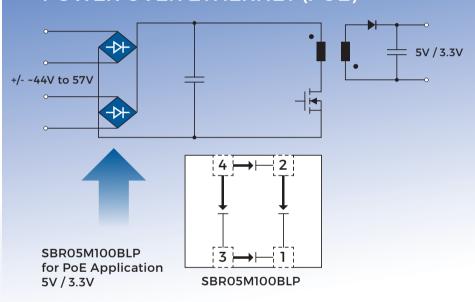
THE **DIODES™** ADVANTAGE

 Improved system efficiency achieved through minimized forward voltage drop (V_F) and reverse leakage current (I_R)

Typical applications

- Smart Home
- Wireless Access Points (WAPs)
- Internet Protocol (IP) cameras
- Voice-over IP (VoIP) phones
- IoT

TYPICAL APPLICATION: POWER OVER ETHERNET (POE)





PoE delivers DC Power over Ethernet cabling, eliminating the need for separate power supplies and outlets.

The bridge rectifier guarantees correct polarity regardless of DC input polarity.

This prevents damage due to non conformant equipment or accidental reverse power connection.





FAST FILTER EMI



Diodes Incorporated (Diodes) is a market leader in both Bridge Rectifier technology and Fast Recovery Rectifier technology. By utilizing these two technologies, we bring to the market a best in class Fast Filter Bridge Rectifier product line-up. This significantly helps the design for EMI-friendly power circuit design, saving PCBA space and requiring less passive components for EMI optimization.

Suitable for AC to DC full wave bridge rectification for SMPS, LED lighting, adapters, battery chargers, home appliances, office equipment, and telecommunication applications.

VRRM	lo	IR Max.	T _{RR}	SOPA-4	MSBL	PIODES	KBP DEODES
V	Α	μA	ns			~	,,,,
	2	1	250	RABS20M	-	-	-
			500	ABS20TIM	-	-	-
1000	7	_	250	-	MRS30M	-	-
1000 3	5	500	-	MSB30TM	-	-	
	,	5	250	-	-	RTT410	RKBP410
4	5	500	_	_	TT4TM	KBP4T10	

THE **DIODES™** ADVANTAGE

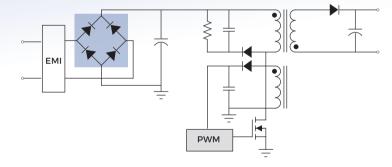
- EMI optimized rectification reduces component count to maximize board real estate
- Improved reliability with robust glass passivated die construction
- 1000V PRV rating

Typical applications

- USB Type-C/USB PD adapters
- Fast charging travel adapters
- Set-top boxes
- Home appliances
- Indoor LED lighting



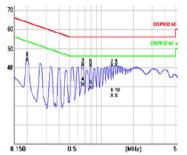
TYPICAL APPLICATION: CHARGER ADAPTER



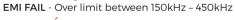
CONDUCTED EMISSION MEASUREMENT

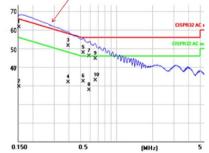
EMC Standard EN55032 CISPR 32

Fast Recovery Bridge MRS30M



Standard Bridge





EMI PASS - The entire blue curve is under the green limit line (AVG).
There is a 10dB difference between the green limit line (AVG) and the red limit line (QP).

SURFACE MOUNT 1A TO 8A, 600V TO 1000V

Diodes' range of space-saving SMD packages provide single phase rectification rated from 1A to 8A and up to 1000V. These products are suitable for AC to DC full wave bridge rectification in a wide range of space-constrained applications including SMPS, LED lighting, adapters, battery chargers, home appliances, office equipment, and telecommunication applications.

1A to 8A

				ABS	HDS	MSBL	TTL
Ю	VRRM	VF Max.	IR Max.	DECOES	Diodes	DODES	DODES
Α	V	V	μΑ			7	7
		0.95	5	ABS10TM	HDS10M	-	-
1	1000	0.95	10	ABS10M	-	-	-
		1.1	1	ABS10(LS)	-	_	-
1.5	1000	1.1	5	-	-	MSB15MH	-
		0.95	5	-	HDS20M	_	-
	1000	0.95	10	ABS20M, ABS20MH	-	-	-
2		1.02	5	-	-	MSB20M	-
		1.1	5	-	-	-	TT2M
2.2	1000	0.92	5	-	-	MSB22ML	-
2.2	1000	1.02	5	-	-	MSB22M	-
2.5	600	0.92	5	-	-	MSB25JL	-
2.5	2.5		5	-	-	MSB25MH	-
	600	0.92	5	-	-	MSB30JL(LS)	-
7	800	1.1	5	– – MS		MSB30KH	-
3	1000	1	5	-	-	-	TT3M(LS)
		1.1	5	-	-	MSB30M	-
		0.95	5	-	-	-	TT4V10
4	1000	1	5	-	-	-	TT4M
		1.3	5	-	-	-	TT4TM
6	600	0.9	5	-	-	-	TT6JL
6	1000	1	5	-	-	-	TT6M
	600	0.9	5	-	-	-	TT8JL
8	1000	1.05	5	-	-	-	TT8M

For our full range visit our website

THE **DIODES™** ADVANTAGE

- Miniature low-profile package saves space
- Improved system efficiency achieved through minimized forward voltage drop (V_F) and reverse leakage current (I_R)
- Robust glass passivated die construction

Typical applications

- 50/60Hz mains rectification
- Power supplies



THROUGH-HOLE 600V TO 1000V



1.5A to 4A

					КВР
Ю	VRRM	VF	IR Max.	IFSM	PRODES
Α	V	٧	μΑ	Α	* * * * * * * * * * * * * * * * * * * *
	600	1.1	5	40	KBP06G
1.5	800	1.1	5	40	KBP08G
	1000	1.1	5	40	KBP10G
	600	1.1	5	65	KBP206G
2	800	1.1	5	65	KBP208G
2	1000	1.1	5	55	KBP2M(LS)
		1.1		65	KBP210G
	600	1.1	5	90	KBP306G
3	800	1.1	5	90	KBP308G
	1000	1.1	5	90	KBP310G
4	600	1.1	5	130	KBP206GL
	800	1.1	5	130	KBP208GL(LS)
	1000	1.1	5	75	KBP4M(LS)
	1000	1.1		130	KBP210GL

THE **DIODES™** ADVANTAGE

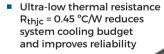
- Improved system efficiency achieved through minimizing forward voltage drop (V_F) and reverse leakage current (I_R)
- Robust glass passivated die construction
- High case dielectric strength
- High surge current capability

Typical applications

- High efficiency SMPS for SPS and server
- White goods

GBJS package

Incorporating a ceramic heat sink providing superior thermal conductivity



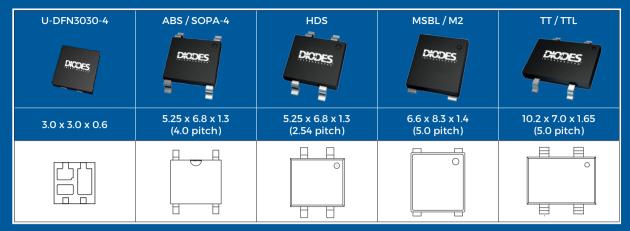


6A to 50A

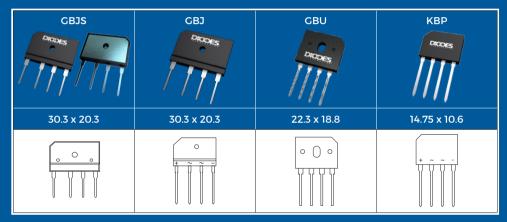
					GBU	GBJ
					650	055
			IR		(20.	DIODES
lo	VRRM	VF	Max.	IFSM	DIODES	
						/ / / /
Α	V	V	μA	Α		, , ,
	600	,	-	170		GBJ606
	600	1	5	175	GBU606	
6	800	1	5	170		GBJ608
0	800	'	5	175	GBU608	
	1000	1	5	170		GBJ610
	1000	'		175	GBU610	
	600	1	5	170		GBJ806
			3	200	GBU806	
	800	1	5	170		GBJ808
8		·		200	GBU808	
				170		GBJ810
	1000	1	5	180	GBU8M(LS)	
				200	GBU810	
		0.92	5	250	GBU10V06	
	600	1	5	220	GBU1006	
		1.05	10	170		GBJ1006
10		0.92	5	250	GBU10V08	
	800	1	5	220	GBU1008	
		1.05	10	170		GBJ1008
	1000	1	5	220	GBU1010	
		1.05	10	170		GBJ1010
	600	0.9	10	200	GBU15L06	GBJ15JL
		105	10	240		GBJ1506
	800	1.05	10	240	CDUITOO	GBJ1508
15		1.1	5	200	GBU1508	CD31EV4O
	1000	0.92	5	400 240		GBJ15V10 GBJ1510
		1.05	10 5	200	GBU1510	GBJISIO
		1.1	10	220	0801310	GBJL1510(LS)
	600	1.05	10	240		GBJ2006
20	800	1.05	10	240		GBJ2008
20	1000	1.05	10	240		GBJ2010
	1000	1.05	10	250	GBU25JL	GB32010
	600	0.92	10	320	GB02332	GBJ25L06
		1.05	10	350		GBJ2506
25	800	0.94	5	600		GBJ25V08
		1.05	10	350	GBU25KH	GBJ2508
		1	5	300		GBJ25M(LS)
		1.05	10	350	GBU2510	GBJ2510
30	800	1.1	10	350	GBU3008	
	1000	1.05	5	270		GBJS3010(LS)**
	600	0.92	10	400		GBJ35JL
35	800	1.1	10	400		GBJ3508
	1000	1.1	10	400		GBJ3510
40	1000	1,1	5	360		GBJS4010**
50	1000	1.1	10	500		GBJ5010(LS)
						, ,

^{**} GBJS Package For our full range visit our website

PACKAGE DIMENSIONS



Dimensions in mm



For our full range of bridge rectifiers visit: www.diodes.com/products/discrete/diodes-and-rectifiers/rectifiers/bridges

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